## High Performance, Low Noise Boost Converter

## General Description

The RT9270 is a high performance, low noise, fixed frequency step up DC-DC Converter. The RT9270 converters input voltage ranging 2.3 V to 5.5 V into output voltage up to 14 V . Current mode control with external compensation network makes it easy to stabilize the system and keep maximum flexibility. Programmable soft start function minimizes impact on the input power system. Internal power MOSFET with very low $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ provides high efficiency. The RT9270 automatically transits from PWM to PSM (Pulse Skipping Mode) during light load condition further increasing efficiency. 670 kHz and 1.3 MHz operation frequency options provide flexibiltity of minimum output filter size, maximum efficiency and low BOM cost.

The RT9270 also provides comprehensive protection functions such as UVLO, OCP, OTP, OVP and short circuit protection.

## Ordering Information

RT9270 $\quad$ Package Type
F: MSOP-8
Operating Temperature Range
P: Pb Free with Commercial Standard
G: Green (Halogen Free with Commer-
cial Standard)

Note :
RichTek Pb-free and Green products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
Suitable for use in SnPb or Pb -free soldering processes. $\rightarrow 100 \%$ matte tin (Sn) plating.


## Features

- 90\% Efficiency
- $\mathrm{V}_{\text {IN }}$ Operating Range: 2.3 V to 5.5 V
- 1.9A, 0.25 $\Omega$, 16V Internal Power MOSFET
- 670 kHz and 1.3 MHz Operation Frequency
- External Compensation Network
- Programmable Soft Start Function
- Small MSOP8 Package
- Short Circuit Protection , Thermal Shutdown, OVP are included
- RoHS Compliant and 100\% Lead (Pb)-Free


## Applications

- TFT LCD panel
- OLEDDisplay
- PCMCIA Cards
- Portable Device


## Pin Configurations

(TOP VIEW)


MSOP-8

## Typical Application Circuit



Figure 1

## Function Block Diagram



## Operation

The RT9270 is a high efficiency step-up Boost converter with a fixed-frequency, current-mode PWM architecture. It performs fast transient response and low noise operation with appropriate component selection. The output voltage is regulated through a feedback control consisting of an error amplifier, a summing comparator, and several control signal generators (as shown in function block diagram). The feedback reference voltage is 1.24 V . The error amplifier varies the COMP voltage by sensing the FB pin. The slope compensation signal summed with the current -sense signal will be compared with the COMP voltage through the summing comparator to determine the current trip point and duty cycle. When driving light loads, the RT9270 will perform the pulse-skipping mode to prevent overcharging the output voltage. In this mode, the switching frequency will be reduced to perform a higher efficiency.

## Soft-Start

The RT9270 provides soft-start function. When the EN pin is connected to high, a 4uA constant current is sourced to charge an external capacitor. The voltage rate of rise on the COMP pin is limited during the charging period, and so is the peak inductor current. When the EN pin is connected to GND, the external capacitor will be discharged to ground for the next time soft-start.

## Current Limitation

The switch current is monitored to limit the value not to exceed 1.9A typically. When the switch current reaches 1.9A, the output voltage will be pulled down to limit the total output power to protect the power switch and external components.

## Shutdown

Connect the EN to GND to turn the RT9270 off and reduce the supply current to 0.1 uA . In this operation, the output voltage is the value of VIN to subtract the forward voltage of catch diode.

## Frequency Selection

The switching frequency of RT9270 can be selected to operate at either 670 kHz or 1.3 MHz . When the FREQ pin is connected to GND for 670 kHz operation, and connected to VIN for 1.3 MHz operation. FREQ is preset to 670 kHz operation for allowing the FREQ pin unconnected.

## Pin Description

## COMP (Pin 1)

Compensation Pin for Error Amplifier. Connect a compensation network to ground. See the Component Selection Table for the loop compensation.

## FB (Pin 2)

Feedback Pin. Connect an external resistor-divider tap to FB. The reference voltage is 1.24 V and set $\mathrm{V}_{\text {оut }}$ according to: $\mathrm{V}_{\text {OUt }}=1.24 \mathrm{~V}(1+\mathrm{R} 1 / \mathrm{R} 2)$. See Figure 1.

## EN (Pin 3)

Shutdown Control Input. Connect EN to GND to turn off the RT9270.

## GND (Pin 4)

Ground.

## LX (Pin 5)

Switch Pin. Connect the inductor and catch diode to LX pin. Widen and shorten the connected trace to minimize EMI.

VIN (Pin 6)
Supply Pin. Place at least a 1 uF ceramic capacitor close to RT9270 for bypassing noise.

## FREQ (Pin 7)

Frequency Select Pin. Oscillator frequency is 670 kHz as FREQ connected to GND, and 1.3 MHz as FREQ connected to VIN. A 5uA pull-down current is sinking on this pin.

## SS (Pin 8)

Soft-Start Control Pin. Connect a soft-start capacitor (Css) to this pin. A 4uA constant current charges the soft-start capacitor. When EN connected to GND, the soft-start capacitor is discharged. When EN connected to VIN high, the soft-start capacitor is charged to VIN. Leave floating for not using soft-start.
Absolute Maximum Ratings (Note 1)

- Supply Voltage, ViN ..... -0.3 to 6 V
- LX to GND -0.3 V to 16 V
- The other pins ..... -0.3 V to 6 V
- Power Dissipation, $\mathrm{P}_{\mathrm{D}}$ @ $\mathrm{T}_{\mathrm{A}}=70^{\circ} \mathrm{C}$MSOP-8300 mW
- Junction Temperature ..... $150^{\circ} \mathrm{C}$
- Lead Temperature (Soldering, 10 sec .) ..... $260^{\circ} \mathrm{C}$
- Operation Temperature Range ..... $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$
- Storage Temperature Range ..... $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$- ESD Susceptibility (Note 2)HBM (Human Body Mode)2kV
MM (Machine Mode) ..... 200V
Recommended Operating Conditions (Note 3)
- Ambient Temperature Range ..... $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$
- Junction Temperature Range ..... $0^{\circ} \mathrm{C}$ to $125^{\circ} \mathrm{C}$


## Electrical Characteristics

$\left(\mathrm{V}_{\mathrm{IN}}=3 \mathrm{~V}, \mathrm{FREQ}\right.$ left floating, $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, Unless Otherwise specification)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| System Supply Input |  |  |  |  |  |  |
| Operation voltage Range | VIN | FREQ = GND | 2.3 | -- | 5.5 | V |
|  |  | FREQ $=\mathrm{V}_{\text {IN }}$ | 2.5 | -- | 5.5 |  |
| Under Voltage Lock Out | UVLO |  | 2 | 2.2 | 2.3 | V |
| Power On Reset Hysteresis |  |  | -- | 200 | -- | mV |
| Quiescent Current | In | $\mathrm{V}_{\mathrm{FB}}=1.3 \mathrm{~V}$, No switching | -- | 270 | 600 | uA |
|  | IN | $\mathrm{V}_{\mathrm{FB}}=1.0 \mathrm{~V}$, Switching, No load | -- | 1.76 | 5 | mA |
| Shut Down Current | In | EN = GND | -- | -- | 1 | uA |
| Soft start Current | Iss |  | -- | 4 | 9 | uA |
| Switching Regulator Oscillator |  |  |  |  |  |  |
| Free Run Frequency | fosc | FREQ=GND | 520 | 670 | 850 | kHz |
|  |  | FREQ $=\mathrm{V}_{\text {IN }}$ | 960 | 1300 | 1500 | kHz |
| Maximum Duty Cycle (Note 4) |  | FREQ = GND | 82 | 90 | 96 | \% |
|  |  | FREQ $=\mathrm{V}_{\text {IN }}$ | 74 | 77 | 80 |  |
| Reference Voltage |  |  |  |  |  |  |
| Feedback Voltage | $V_{\text {FB }}$ |  | 1.216 | 1.24 | 1.264 | V |
| Error Amplifier |  |  |  |  |  |  |
| GM |  | (Note 4) | -- | 1.1 | -- | ms |
| Feedback Voltage Line Regulation |  | $2.3 \mathrm{~V}<\mathrm{V}_{\mathrm{IN}}<5.5 \mathrm{~V}$ | -- | 0.12 | 0.3 | \%/V |


| Parameter | Symbol | Test Condition | Min | Typ | Max | Units |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MOSFET | O |  |  |  |  |  |
| On Resistance of MOSFET | $\mathrm{R}_{\mathrm{DS}(\mathrm{ON})}$ |  | -- | 250 | 550 | $\mathrm{~m} \Omega$ |
| Current Limitation |  |  | -- | 1.9 | -- | A |

Note 1. Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

Note 2. Devices are ESD sensitive. Handling precaution recommended.
Note 3. The device is not guaranteed to function outside its operating conditions.
Note 4. Guaranteed by Design.

## Typical Operating Characteristics





$\mathrm{V}_{\mathrm{FB}}$ vs. Temperature


No Load Supply Current vs. VIN


Maximum Output Current vs. $\mathrm{V}_{\mathrm{IN}}$








OCP Waveform


## OTP Waveform




Component Selection Table

| $V_{\text {IN }}$ <br> $(\mathrm{V})$ | VOUT <br> $(\mathrm{V})$ | fosc <br> $(\mathrm{Hz})$ | L1 <br> $(\mathrm{uH})$ | C 2 <br> $(\mathrm{uF})$ | R 3 <br> $(\mathrm{k} \Omega)$ | C 3 <br> $(\mathrm{pF})$ | C 4 <br> $(\mathrm{pF})$ | Typical IOUT(MAX) <br> $(\mathrm{mA})$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3.3 | 12 | 670 k | 10(TDK SLF6028) | 33 tantalum | 36 | 1200 | 33 | 250 |
| 3.3 | 12 | 670 k | 4.7 (TDK SLF6028) | 33 tantalum | 47 | 1000 | 22 | 250 |
| 3.3 | 12 | 1.3 M | 10 (TDK SLF6028) | 33 tantalum | 39 | 1000 | 33 | 210 |
| 3.3 | 12 | 1.3 M | 4.7 (TDK SLF6028) | 33 tantalum | 51 | 820 | 22 | 210 |
| 3.3 | 7.2 | 670 k | 4.7 (TDK SLF6028) | 47 tantalum | 22 | 820 | 56 | 490 |
| 3.3 | 7.2 | 1.3 M | 4.7 (TDK SLF6028) | 47 tantalum | 32 | 1000 | 56 | 450 |

## Application Information

The design procedure of Boost converter can start from the maximum input current, which is related about inductor, catch-diode, input/output capacitor selections and the maximum power which internal switch can stand. It can be derived from maximum output power, minimum input voltage and the efficiency of Boost converter. Once the maximum input current is calculated, the inductor value can be determined and the other components as well.

## Inductor Selection

For a better efficiency in high switching frequency converter, the inductor selection has to use a proper core material such as ferrite core to reduce the core loss and choose low ESR wire to reduce copper loss. The most important point is to prevent the core saturated when handling the maximum peak current. Using a shielded inductor can minimize radiated noise in sensitive applications. The maximum peak inductor current is the maximum input current plus the half of inductor ripple current. The calculated peak current has to be smaller than the current limitation in the electrical characteristics. A typical setting of the inductor ripple current is $20 \%$ to $40 \%$ of the maximum input current. If the selection is $40 \%$, the maximum peak inductor current is :

$$
\begin{aligned}
\operatorname{IPK} & =\operatorname{IIN}(\operatorname{MAX})+\frac{1}{2} \operatorname{IRIPPLE}=1.2 \times \operatorname{IIN}(\mathrm{MAX}) \\
& =1.2 \times\left[\frac{\operatorname{IOUT}(\mathrm{MAX}) \times \operatorname{VOUT}}{\eta \times \operatorname{VIN}(\mathrm{MIN})}\right]
\end{aligned}
$$

The minimum inductance value is derived from the following equation :

$$
\mathrm{L}=\frac{\eta \times \operatorname{VIN}(\mathrm{MIN}){ }^{2} \times[\mathrm{VOUT}-\mathrm{VIN}(\mathrm{MIN})]}{0.4 \times \operatorname{IOUT}(\mathrm{MAX}) \times \mathrm{VOUT}^{2} \times \mathrm{fOSC}}
$$

Depending on the application, the recommended inductor value is between 2.2 uH and 10 uH .

## Diode Selection

To achieve high efficiency, Schottky diode is good choice for low forward drop voltage and fast switching time. The output diode rating should be able to handle the maximum output voltage, average power dissipation and the pulsating diode peak current.

## Input Capacitor Selection

For better input bypassing, low-ESR ceramic capacitors are recommended for performance. A 10 uF input capacitor is sufficient for most applications. For a lower output power requirement application, this value can be decreased.

## Output Capacitor Selection

For lower output voltage ripple, low-ESR ceramic capacitors are recommended. The tantalum capacitors can be used as well, but the ESR is bigger than ceramic capacitor. The output voltage ripple consists of two components: one is the pulsating output ripple current flows through the ESR, and the other is the capacitive ripple caused by charging and discharging.

$$
\begin{aligned}
& \text { VRIPPLE }=\text { VRIPPLE }(E S R)+\text { VRIPPLE }(C) \\
& \cong \text { IPEAK } \times \text { ESRCout }+\frac{\text { IPEAK }}{\text { COUT }}\left(\frac{\text { VOUT }- \text { VIN }}{\text { VOUT } \times \text { fOSC }}\right)
\end{aligned}
$$

## Output Voltage

The regulated output voltage is calculated by :

$$
\text { Vout }=1.24 \mathrm{~V} \times\left(1+\frac{\mathrm{R} 1}{\mathrm{R} 2}\right)
$$

For most applications, R2 is a suggested a value up to $100 \mathrm{k} \Omega$. Place the resistor-divider as close to the IC as possible to reduce the noise sensitivity.

## Loop Compensation

The RT9270 voltage feedback loop can be compensated with an external compensation network consisted of R3, C3 and C4 (As shown in Figure 1). Choose R3 to set the high-frequency integrator gain for fast transient response without over or under compensation. Once R3 is determined, C 3 is selected to set the integrator zero to maintain loop stability. The purpose of C 4 is to cancel the zero caused by output capacitor and the capacitor ESR. If the ceramic capacitor is selected to be the output capacitor, C4 can be taken off because of the small ESR.

C2 is the output capacitor as shown in Figure 1. The following equations give approximate calculations of each component :

$$
\begin{align*}
& \mathrm{C} 3=\frac{2}{\mathrm{C} 2 \times \mathrm{RL}} \times 10^{-12}  \tag{F}\\
& \mathrm{R} 3=\frac{\mathrm{V}) \times \sqrt{\mathrm{L} 1 \times \mathrm{C} 2}}{2 \times \mathrm{C} 3 \times \mathrm{VIN}} \\
& \mathrm{C} 4=\mathrm{C} 2 \times \mathrm{RESR} \times 1 \times 10^{-6} \tag{F}
\end{align*}
$$

The best criterion to optimize the loop compensation is by inspecting the transient response and adjusting the compensation network.

## Soft-Start Capacitor

The soft-start function begins from $\mathrm{V}_{\mathrm{SS}}=0 \mathrm{~V}$ to $\mathrm{V}_{\mathrm{SS}}=1.24 \mathrm{~V}$ with a 4 uA constant current charging to the soft-start capacitor, so the capacitor should be large enough to let the output voltage reach regulation inside the soft-start cycle. Typical value of soft-start capacitor range is from 10nF to 200nF. After the cycle finished, the load can start to draw maximum current as required.

## Layout Guideline

For high frequency switching power supplies, the PCB layout is important step in system application design. In order to let IC achieve good regulation, high efficiency and stability, it is strongly recommended the power components should be placed as close as possible. These traces should be wide and short. The feedback pin and the networks of feedback and compensation should be kept away from the power loops, and be shielded with a ground trace or plane to prevent noise coupling.


EVB Circuit


Top Side


Bottom Side

## Outline Dimension



| Symbol | Dimensions In Millimeters |  | Dimensions In Inches |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Min | Max | Min | Max |
| A | 0.810 | 1.100 | 0.032 | 0.043 |
| A1 | 0.000 | 0.150 | 0.000 | 0.006 |
| A2 | 0.750 | 0.950 | 0.030 | 0.037 |
| b | 0.220 | 0.380 | 0.009 | 0.015 |
| D | 2.900 | 3.100 | 0.114 | 0.122 |
| e | 0.650 |  |  |  |
| E | 4.800 | 5.000 | 0.189 | 0.197 |
| E1 | 2.900 | 3.100 | 0.114 | 0.122 |
| L | 0.400 | 0.800 | 0.016 | 0.031 |

8-Lead MSOP Plastic Package

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